

isc Silicon NPN Power Transistor

DESCRIPTION

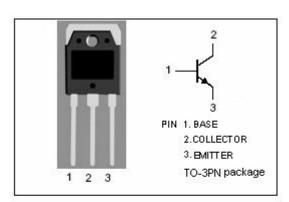
- · High Breakdown Voltage-
 - : V_{(BR)CBO}= 800V(Min)
- · Fast Switching Speed
- · Wide Area of Safe Operation
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

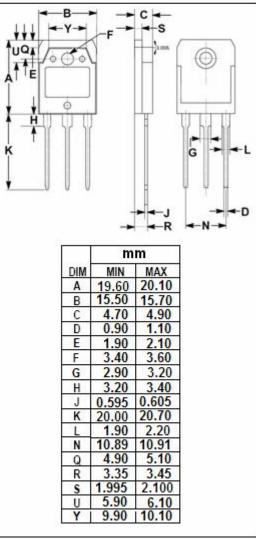
APPLICATIONS

· Designed for switching regulator applications

ABSOLUTE MAXIMUM RATINGS(T_a=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	800	V	
V _{CEO}	Collector-Emitter Voltage	500	V	
V _{EBO}	Emitter-Base Voltage	7	V	
Ic	Collector Current-Continuous	Α		
I _{CM}	Collector Current-Peak 20		Α	
lв	Base Current-Continuous	4	А	
Pc	Collector Power Dissipation @ T _a =25°C	2.5	W	
	Collector Power Dissipation @ Tc=25°C	100		
TJ	Junction Temperature	150	$^{\circ}$	
T _{stg}	Storage Temperature Range	-55~150	$^{\circ}$	







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2SC3090

ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT	
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 5mA; R _{BE} = ∞	500			V	
V _{(BR)CBO}	Collector-Base Breakdown Voltage	I _C = 1mA; I _E = 0	800			V	
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = 1mA; I _C = 0	7			V	
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 6A; I _B = 1.2A			1.0	V	
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 6A; I _B = 1.2A			1.5	V	
I _{CBO}	Collector Cutoff Current	V _{CB} = 500V; I _E =0			10	μА	
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V; I _C =0			10	μА	
h _{FE-1}	DC Current Gain	I _C = 1.2A; V _{CE} = 5V	15		50		
h _{FE-2}	DC Current Gain	Ic= 6A; Vc== 5V	8				
Сов	Output Capacitance	I _E = 0; V _{CB} = 10V; f _{test} =1.0MHz		160		pF	
f⊤	Current-Gain—Bandwidth Product	I _C = 1.2A; V _{CE} = 10V		18		MHz	
Switching times							
ton	Turn-on Time				1.0	μ S	
t _{stg}	Storage Time	I _C = 7A, I _{B1} = -I _{B2} = -1.4A; R _L = 28.6 Ω; V _{CC} = 200V			3.0	μ S	
t _f	Fall Time	_ , 33			1.0	μs	

♦ h_{FE-1} Classifications

L	М	N	
15-30	20-40	30-50	

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